

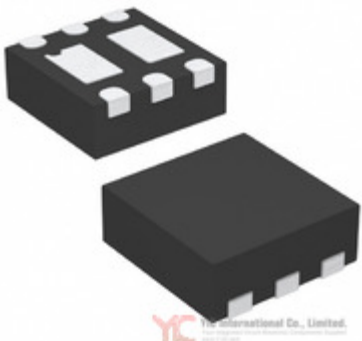


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|---|---|
|  | <p>SIA777EDJ-T1-GE3</p> <p>Hersteller-Teilenummer: SIA777EDJ-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N/P-CH 20V/12V SC70-6L</p> <p>Datenblätter:  SIA777EDJ-T1-GE3.pdf</p> <p>RoHS Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
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| <p>Image may be representation. See specs for product details.</p> | |

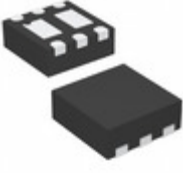
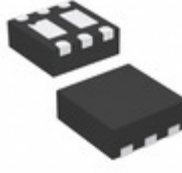
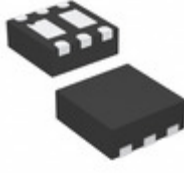
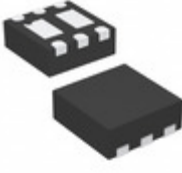
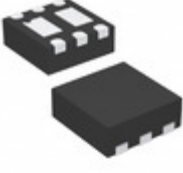
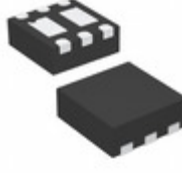
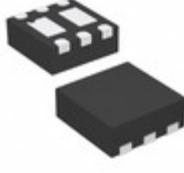
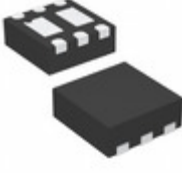
Spezifikationen

| | |
|--|---|
| Teilenummer | SIA777EDJ-T1-GE3 |
| Hersteller | Vishay / Siliconix |
| Beschreibung | MOSFET N/P-CH 20V/12V SC70-6L |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs , |
| Teilstatus | Require For Quote & Check Stock |
| VGS (th) (Max) @ Id | 1V @ 250µA |
| Supplier Device-Gehäuse | PowerPAK® SC-70-6 Dual |
| Serie | TrenchFET® |
| Rds On (Max) @ Id, Vgs | 225 mOhm @ 1.6A, 4.5V |
| Leistung - max | 5W, 7.8W |
| Verpackung | Tape & Reel (TR) |
| Verpackung / Gehäuse | PowerPAK® SC-70-6 Dual |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Eingabekapazität (Ciss) (Max) @ Vds | - |
| Gate Charge (Qg) (Max) @ Vgs | 2.2nC @ 5V |
| Typ FET | N and P-Channel |
| FET-Merkmal | Logic Level Gate |
| Drain-Source-Spannung (Vdss) | 20V, 12V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 1.5A, 4.5A |

SIA777EDJ-T1-GE3 Electronic Components ist ein 100% neues Original von YIC Distributor, SIA777EDJ-T1-GE3-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, SIA777EDJ-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal.

RFQ SIA777EDJ-T1-GE3 E-Mail: Info@Y-IC.com

Sie können auch interessiert

| | | | |
|--|---|---|--|
| <p>sein:</p>  <p>SIA777EDJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V/12V SC70-6L</p> |  <p>SIA533EDJ-T1-GE3 Vishay Siliconix MOSFET N/P-CH 12V 4.5A SC70-6</p> |  <p>SIA537EDJ-T1-GE3 Vishay Siliconix MOSFET N/P-CH 12V/20V SC-70-6L</p> |  <p>SIA778DJ-T1-GE3 Vishay Siliconix MOSFET 2N-CH 12V/20V SC70-6</p> |
|  <p>SIA810DJ-T1-GE3 Vishay Siliconix MOSFET N-CH 20V 4.5A SC70-6</p> |  <p>SIA533EDJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N/P-CH 12V 4.5A SC70-6</p> |  <p>SIA810DJ-T1-E3 Vishay Siliconix MOSFET N-CH 20V 4.5A SC-70-6</p> |  <p>SIA778DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 12V/20V SC70-6</p> |

Verwandtes Hot-Keyword

Mehr

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|---|--|---|--|---|
| SIA777EDJ-T1-GE3 Vishay / Siliconix | SIA777EDJ-T1-GE3 Datenblatt | SIA777EDJ-T1-GE3-Datenblätter | SIA777EDJ-T1-GE3 PDF | Vishay / Siliconix SIA777EDJ-T1-GE3 |
| SIA777EDJ-T1-GE3 Electronic | SIA777EDJ-T1-GE3-Komponenten | SIA777EDJ-T1-GE3-Verteiler | SIA777EDJ-T1-GE3-Bild | SIA777EDJ-T1-GE3-Teil |
| SIA777EDJ-T1-GE3 Preis | SIA777EDJ-T1-GE3 Hersteller | SIA777EDJ-T1-GE3 Bild | SIA777EDJ-T1-GE3 Aktie | SIA777EDJ-T1-GE3 Inventar |
| SIA777EDJ-T1-GE3 Neu | SIA777EDJ-T1-GE3 Original | SIA777EDJ-T1-GE3 garantiert | SIA777EDJ-T1-GE3 RFQ | SIA777EDJ-T1-GE3 Online bestellen |

Contact us: Info@Y-IC.com

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